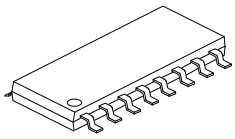
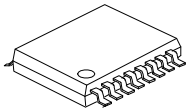
3.0V TO 5.5V LOW POWER MULTICHANNEL RS-232 LINE TRANSCEIVERS USING FOR 0.1μF EXTERNAL CAPACITORS



SOP-16



TSSOP-16

■ DESCRIPTION

The UTC **UT3232** have two receivers and two drivers, and a dual charge-pump circuit. The device meets the requirements of TIA/EIA-232-F and provides the electrical interface between an asynchronous communication controller and the serial-port connector. The charge pump and four small external capacitors allow operation from a single 3.0V to 5.5V supply. The device operates at data signaling rates up to 250kbit/s and a maximum of 35V/μs driver output slew rate.

■ FEATURES

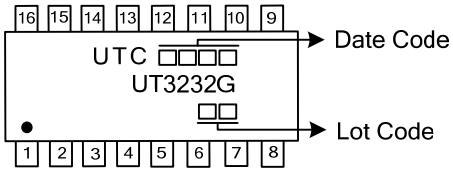
* Exceeds ±8KV ESD Protection(HBM) for RS-232 I/O Pins
* Meets the Requirements of TIA/EIA-232-F and ITU V.28 Standards
* Operates With 3.0V to 5.5V V_{CC} Supply
* Operates Up To 250kbit/s Data Rate
* Two Drivers and Two Receivers
* External Capacitors 4×0.1μF
* Accepts 5.0V Logic Input With 3.3V Supply

■ ORDERING INFORMATION

Ordering Number	Package	Packing
UT3232G-S16-R	SOP-16	Tape Reel
UT3232G-P16-R	TSSOP-16	Tape Reel

UT3232G-S16-R (1)Packing Type (2)Package Type (3)Green Package	(1) R: Tape Reel (2) S16: SOP-16, P16: TSSOP-16 (3) G: Halogen Free and Lead Free

■ MARKING



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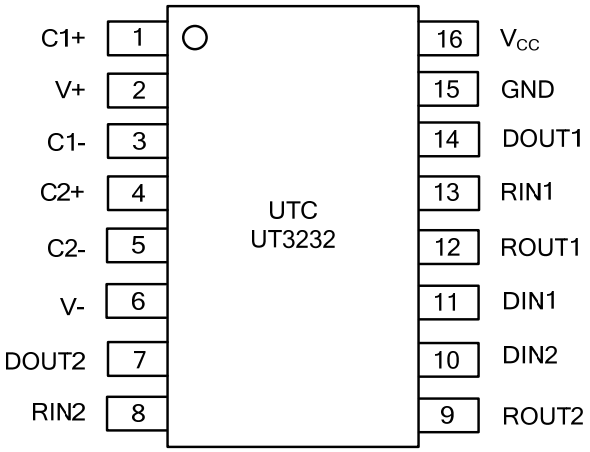
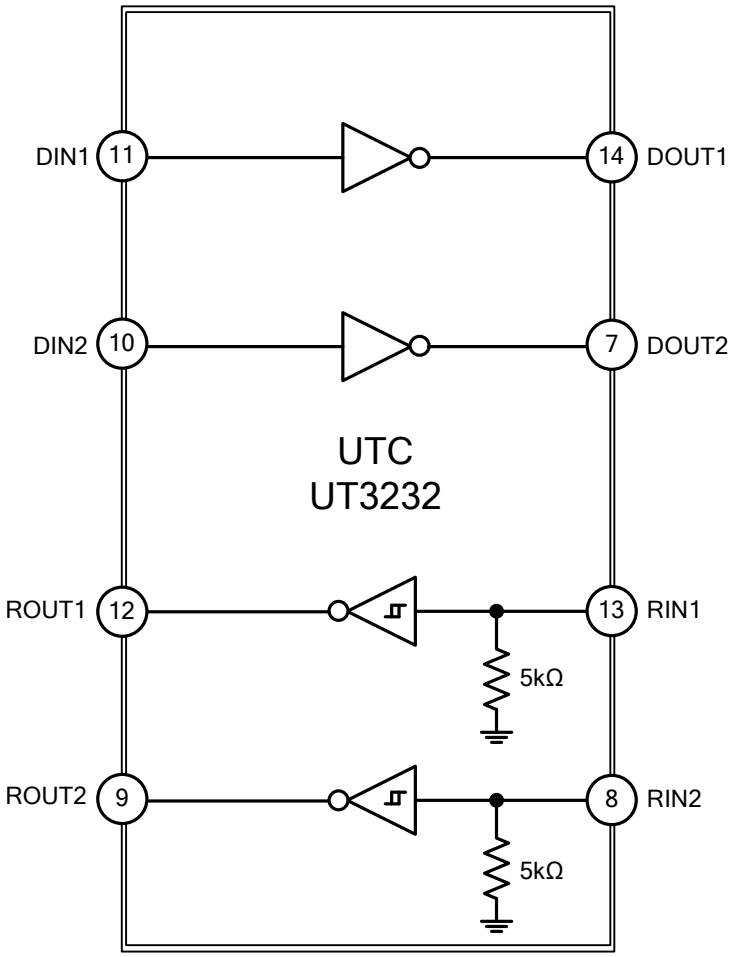
■ PIN CONFIGURATION



■ PIN DESCRIPTION

PIN NO.	PIN NAME	DESCRIPTION
1	C1+	Positive Terminal of Voltage-Doubler Charge-Pump Capacitor
2	V+	+5.5V Generated by the Charge Pump
3	C1-	Negative Terminal of Voltage-Doubler Charge-Pump Capacitor
4	C2+	Positive Terminal of Inverting Charge-Pump Capacitor
5	C2-	Negative Terminal of Inverting Charge-Pump Capacitor
6	V-	-5.5V Generated by the Charge Pump
7	DOUT2	RS-232 Driver Outputs
8	RIN2	RS-232 Receiver Inputs
9	ROUT2	TTL/CMOS Receiver Outputs
10	DIN2	TTL/CMOS Driver Inputs
11	DIN1	TTL/CMOS Driver Inputs
12	ROUT1	TTL/CMOS Receiver Outputs
13	RIN1	RS-232 Receiver Inputs
14	DOUT1	RS-232 Driver Outputs
15	GND	Ground
16	V_{CC}	+3.0V to +5.5V Supply Voltage

■ BLOCK DIAGRAM



■ ABSOLUTE MAXIMUM RATING [Over operating free-air temperature range (unless otherwise noted)]

PARAMETER		SYMBOL	RATINGS	UNIT
Supply Voltage Range		V_{CC}	-0.3 ~ +6.0	V
Positive Output Supply Voltage Range (Note 2)		V+	-0.3 ~ +7.0	V
Negative Output Supply Voltage Range (Note 2)		V-	+0.3 ~ -7.0	V
Supply Voltage Difference (Note 2)		V+ - V-	+13	V
Input Voltage	Drivers	V_{IN}	-0.3 ~ +6.0	V
	Receivers		-25 ~ +25	V
Output Voltage	Drivers	V_{OUT}	-13.2 ~ +13.2	V
	Receivers		-0.3 ~ V_{CC}+0.3	V
Operating Virtual Junction Temperature		T_J	+150	°C
Storage Temperature		T_{STG}	-65 ~ + 150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
2. All voltages are with respect to network GND.

■ THERMAL DATA

PARAMETER		SYMBOL	RATING	UNIT
Junction to Ambient	SOP-16	θ_{JA}	105	°C/W
	TSSOP-16		118	

■ RECOMMENDED OPERATING CONDITIONS (See Note & Table 1)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Supply Voltage	V_{CC}	V_{CC}=3.3V		3.0	3.3	3.6	V
		V_{CC}=5.0V		4.5	5.0	5.5	V
Driver and Control High-level Input Voltage	V_{IH}	DIN	V_{CC}=3.3V	2.0			V
			V_{CC}=5.5V	2.4			
Driver and Control Low-level Input Voltage	V_{IL}	DIN				0.8	V
Driver and Control Input Voltage	V_{IN}	DIN				5.5	V
Receiver Input Voltage	V_{RIN}			-25		25	V
Operating Free-Air Temperature	T_A			0		70	°C

Notes: Test conditions are C1~C4=0.1μF at V_{CC}=3.3V±0.3V; C1=0.047μF, C2~C4=0.33μF at V_{CC}=5.0V±0.5V.

■ ELECTRICAL CHARACTERISTICS [(over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 & Table 1)]

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP (Note 1)	MAX	UNIT
Input Leakage Current	I_{IN}	DIN		±0.01	±1	μA
Supply Current	I_{CC}	No load		0.3	1.0	mA
DRIVER SECTION						
High-Level Output Voltage	V_{OH}	DOUT at R_L=3kΩ to GND, DIN=GND	+5.0	+5.4		V
Low-Level Output Voltage	V_{OL}	DOUT at R_L=3kΩ to GND, DIN=V_{CC}	-5.0	-5.4		V
High-Level Input Current	I_{OH}	V_I=V_{CC}		±0.01	±1	μA
Low-Level Input Current	I_{OL}	V_I at GND		±0.01	±1	μA
Short-Circuit Output Current (Note 2)	I_{OS}	V_{CC}=3.6V, V_{OUT}=0V		±35	±60	mA
		V_{CC}=5.5V, V_{OUT}=0V		±35	±60	mA
Output Resistance	r_O	V_{CC}, V+ and V- =0V, V_{OUT}=±2.0V	300	10M		Ω
Output Leakage Current	I_{OFF}	V_{CC}=3.0V~5.5V, V_{OUT}=±12V			±25	μA
RECEIVER SECTION						
High-Level Output Voltage	V_{OH}	I_{OH}=-1.0mA	V_{CC}-0.6V	V_{CC}- 0.1V		V
Low-Level Output Voltage	V_{OL}	I_{OL}=1.6mA			0.4	V
Positive-Going Input Threshold Voltage	V_{IT+}	V_{CC}=3.3V		1.5	2.4	V
		V_{CC}=5.0V		1.8	2.4	V
Negative-Going Input Threshold Voltage	V_{IT-}	V_{CC}=3.3V	0.6	1.2		V
		V_{CC}=5.0V	0.8	1.5		V
Input Hysteresis	V_{HYS}	V_{IT+}~V_{IT-}		0.3		V
Output Leakage Current	I_{OFF}			±0.05	±10	μA
Input Resistance	R_I	V_I=±3.0V~±25V	3	5	7	kΩ

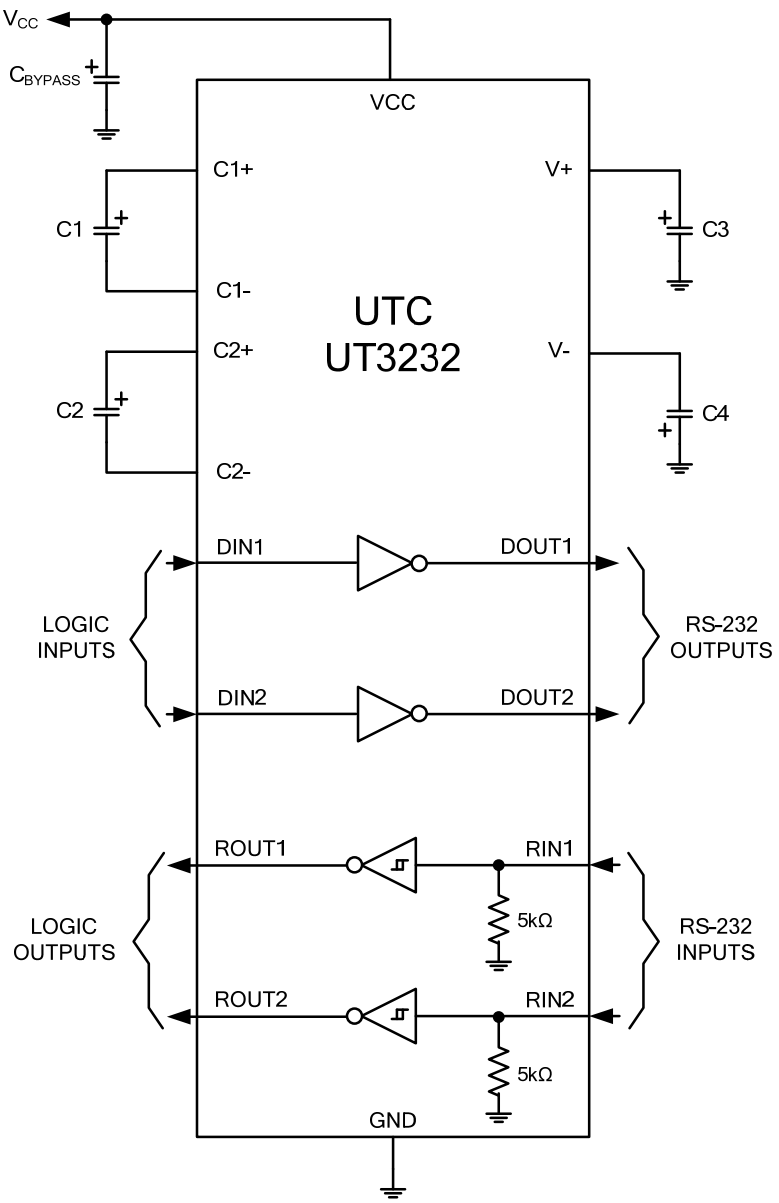
Notes: 1. All typical values are at V_{CC}=3.3V or V_{CC}=5.0V, and T_A=25°C.
2. Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.
3. Test conditions are C1~C4=0.1μF at V_{CC}=3.3V±0.3V; C1=0.047μF, C2~C4=0.33μF at V_{CC}=5.0V±0.5V.
4. Pulse skew is defined as $|t_{PLH}-t_{PHL}|$ of each channel of the same device.

■ SWITCHING CHARACTERISTICS [over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Note 3 and Table 1)]

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP (Note 1)	MAX	UNIT
DRIVER SECTION							
Maximum Data Rate		C_L=1000pF, R_L=3kΩ, One Driver Switching		150	250		Kbit/s
Pulse Skew (Note 4)	$t_{SK(p)}$	C_L=220pF~2500pF, R_L =3kΩ~7kΩ			300		ns
Slew Rate, Transition Region	SR(tr)	R_L =3kΩ~7kΩ, V_{CC}=3.3V	C_L=220pF~1000pF	5		35	V/μs
			C_L=220pF~2500pF	3		35	
RECEIVER SECTION							
Propagation Delay Time, Low-to High-Level Output	t_{PLH}	C_L=150pF			300		ns
Propagation Delay Time, High-to Low-Level Output	t_{PHL}	C_L=150pF			300		ns
Output Enable Time	t_{EN}	C_L=150pF, R_L=3kΩ			200		ns
Output Disable Time	t_{DIS}	C_L=150pF, R_L=3kΩ			200		ns
Pulse Skew (Note 4)	$t_{SK(P)}$	$\|t_{PLH}-t_{PHL}\|$			300		ns

Notes: 1. All typical values are at V_{CC}=3.3V or V_{CC}=5.0V, and T_A=25°C.
2. Short-circuit durations should be controlled to prevent exceeding the device absolute power-dissipation ratings, and not more than one output should be shorted at a time.
3. Test conditions are C1~C4=0.1μF at V_{CC}=3.3V±0.3V; C1=0.047μF, C2~C4=0.33μF at V_{CC}=5.0V±0.5V.
4. Pulse skew is defined as $|t_{PLH}-t_{PHL}|$ of each channel of the same device.

■ TYPICAL APPLICATION CIRCUIT



Notes: 1. C3 can be connected to V_{CC} or GND.
2. Resistor values shown are nominal.
3. NC: No internal connection.
4. Nonpolarized ceramic capacitors are acceptable. If polarized tantalum or electrolytic capacitors are used, they should be connected as shown.

Table1. Typical Operating Circuit and Capacitor Values

V_{CC} (V)	C1 (μF)	C2, C3, C4 (μF)	C_{BYPASS} (μF)
3.0~3.6	0.22	0.22	0.22
3.15~3.6	0.1	0.1	0.1
4.5~5.5	0.047	0.33	0.047
3.0~5.5	0.22	1.0	0.22

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